

Ultra-Low Jitter Crystal Oscillators (VCXO)

Features

- Available at any frequency from 20 MHz to 2000 MHz
- Jitter as low as 20 fs (12 KHz to 20 MHz)
- Total stability of ± 5 ppm
- Programmable tuning slope (Kvco) up to 300 ppm/V
- CML/LVDS/LVPECL/HCSL output formats
- Simplified BoM with no external loop filters
- Output Enable/Disable Feature
- < 10 ms start-up time
- No activity dips or micro jumps
- Industry standard 3.2X2.5 mm 8-pin LGA package
- Single 1.8V supply with internal regulator
- Superior power supply immunity
- Temperature range: -40°C to 85°C
- Temperature extended range: -40°C to 105°C
- ESD HBM 2000V, CDM 500V
- Lead free / RoHS compliant

Applications

- SONET/SDH
- 10 GbE LAN/WAN
- Wireless Infrastructure
- Synchronous Ethernet
- Optical modules
- Clock and data recovery
- Clock Generation and Frequency Translation
- High-performance replacement for SAW



General Description

The MS1240 is a voltage-controlled crystal oscillator (VCXO) powered by our Virtual Crystal™ technology that enables ultra stable fully programmable multi-GHz clocks with extremely low phase noise.

Adaptive fully autonomous DSP algorithms running in the background continuously monitor and ensure robust and consistent performance over process, voltage, and temperature variations.

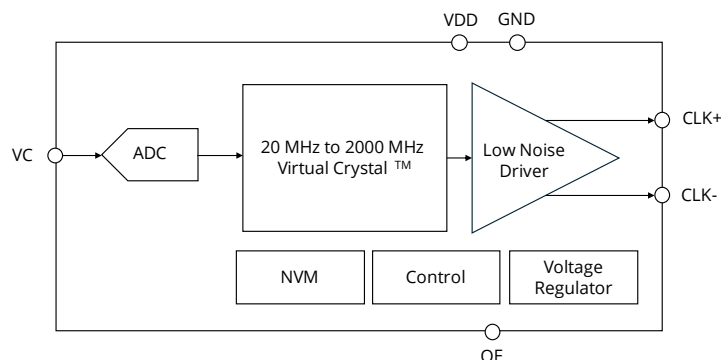
The devices are factory programmed to provide any frequency between 20 MHz and 2000 MHz with less than 1 ppb resolution.

The MS1240 is manufactured in a high-volume 28 nm CMOS process and represents the most advanced node in the timing industry.

Device Information

Part Number	Package	Description
MS1240	3.2X2.5 mm 8-pin LGA	Single frequency

Figure 1. Functional Block Diagram



MS1240

Single Frequency Device

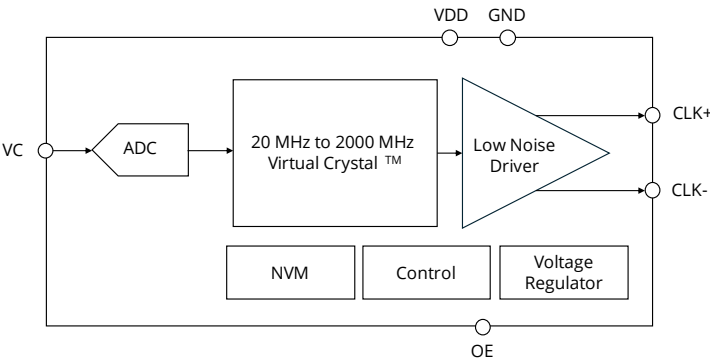


Figure 2. MS1240 Functional Block Diagram

Pin Assignment and Pin Description

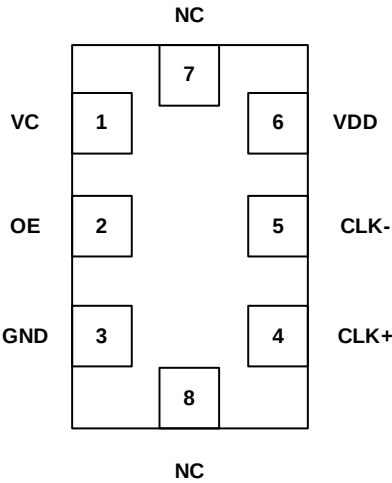


Figure 3. MS1240 Pin Assignments

Table 1. MS1240 Pin Descriptions

Pin No	Name	Description
1	VC	Control Voltage
2	OE	Output Enable
3	GND	Ground
4	CLK+	Clock Output
5	CLK-	Complementary Clock Output
6	VDD	Power Supply
7	NC	No Connect
8	NC	No Connect

Specifications

Table 2. Electrical Specifications

Typical values are specified at $T_A = 25^\circ\text{C}$, $V_{DD} = 1.8\text{V}$ unless otherwise specified. All Min and Max limits are specified over the operating temperature range and voltage range with standard termination. A 0.1uF and 10uF bypass capacitor should be connected between VDD and GND pins located close to the device.

Parameter	Symbol	Test Condition/Comment	Min	Typ	Max	Unit
-----------	--------	------------------------	-----	-----	-----	------

Frequency Range

Frequency Range	F_{CLK}	All Output Formats	20		2000	MHz
-----------------	-----------	--------------------	----	--	------	-----

Frequency Stability

Frequency Stability	F_{STB}	-40°C to 85°C Inclusive of initial accuracy, operating temp, voltage tolerance and aging	-5		5	PPM
Frequency Stability	F_{STB}	-40°C to 105°C Inclusive of initial accuracy, operating temp, voltage tolerance and aging	-20		20	PPM

Clock Output Jitter Characteristics

RMS Phase Jitter (12 KHz – 20 MHz)	Φ_{JITTER}	Frequency=312.5 MHz		30		fs
---------------------------------------	-----------------	---------------------	--	----	--	----

Note:

Phase jitter measured on Agilent 5052B Signal Source Analyzer

Operating Voltage/Temperature Range

Supply Voltage	V_{DD}		1.71	1.8	1.89	V
Temperature Range	T_A	Industrial Temperature	-40		85	°C
		Extended Industrial Temperature	-40		105	°C

Current Consumption

Supply Current	I_{DD}	LVDS Output (Output Enabled)		135	162	mA
		All Other Outputs (Output Enabled)		145	174	mA
		Tristate Hi-Z (Output Disabled)		70	84	mA

Input Characteristics

Digital Input Levels (OE/FS)	V_{IH}		$0.7XV_{DD}$			V
	V_{IL}				$0.3XV_{DD}$	V
Output Enable (OE)	T_D	Output Disable Time			3	us
	T_E	Output Enable Time			20	us
Powerup Time	T_{PWR}	Time from $0.9xV_{DD}$ until output frequency (F_{CLK}) within spec			10	ms

PSRR Characteristics

PSRR	$PSRR_{SPUR}$	Spurs induced by 50mV power supply ripples (All frequency, all output types)		-100		dBc
------	---------------	--	--	------	--	-----

Note:

- (1) Measured maximum spur level with 50mVpp sinusoidal signal between 50 kHz and 1 MHz applied on VDD Pin

Output Characteristics

Output Duty Cycle	DC	All Output Formats	48		52	%
Output Rise/Fall Time (20% to 80% V_{PP})	T_R / T_F	All Output Formats		65	100	ps
LVDS Output (AC Mode)	V_O	Swing (Diff)	0.5	0.7	0.9	V
LVDS Extended Output (AC Mode)	V_O	Swing (Diff)	0.8	1.2	1.6	V
CML Output (AC Mode)	V_O	Swing (Diff)	0.7	0.85	1	V
LVPECL Output (AC Mode) Integrated Termination	V_O	Swing (Diff)	1.2	1.4	1.6	V
HCSL Output Integrated Termination	V_O	Swing (Diff)	1.2	1.4	1.6	V

Vc Control Voltage Input

Parameter	Symbol	Test Condition/Comment	Min		Typ	Max	Unit
Control Voltage Tuning Slope ¹	Kvco	0.1V to 0.9V			50		ppm/V
					100		
					150		
					200		
					250		
					300		
Control Voltage Linearity	Lvc	Best Straight Line Fit	-1.5		±0.5	+1.5	%
		KVCO Variation	-10		±5	+10	%
Modulation Bandwidth	BW				10		kHz
Vc Input Impedance	Zvc		500				kΩ
Nominal Control Voltage	Vcnom	@fo			0.5		V
Control Voltage Tuning Range	Vc		0.1			0.9	V

Table 3. Absolute Maximum Ratings

Parameter	Min	Max	Unit
1.8V Supply Voltage	-0.3	1.98	V
Digital I/O	-0.3	1.98	V
Maximum Operating Temperature		105	°C
Storage Temperature	-55	150	°C
Soldering Temperature		260	°C
Junction Temperature		150	°C
Note: Stresses that exceed what is listed in this table may cause permanent damage to the device. Exposure to conditions above the recommendations for extended periods of time may affect device reliability.			

Table 4. Package Thermal Information

Package	Parameter	Symbol	Value	Unit
3.2mmX2.5mm 8 pin LGA	Thermal Resistance, Junction to Ambient	θ_{JA}	80	°C/W
	Thermal Resistance, Junction to Board	θ_{JB}	40	°C/W
	Air Flow Condition		0	mps
	Maximum Junction Temperature	T_J	125	°C
Note: The thermal resistance information stated in this table is based on a standard JEDEC PCB condition. The actual thermal resistance varies depending on the customer PCB design.				

Table 5. Environmental Compliance

Parameter	Test Condition
Mechanical Shock	MIL-STD-883, Method 2002
Mechanical Vibration	MIL-STD-883, Method 2007
Moisture Sensitivity Level (MSL)	3
Note: For additional information not listed, please contact Mixed-Signal Devices.	

Table 6. ESD Levels

Description	Description	Specification	Level
HBM ¹	Human Body Model	JEDEC JS-001	2000V
CDM ²	Charge Device Model	JEDEC JESD22-C101	500V
Notes: 1. 1000V HBM allows safe manufacturing with standard ESD control process – JEDEC document JEP155 2. 250V CDM allows safe manufacturing with standard ESD control process – JEDEC document JEP157			

Table 7. Clock Output Jitter Characteristics¹VDD= 1.8V±5%, T_A= Operating Temperature

Parameter	Test Conditions	Min	Typ	Max	Unit
RMS Phase Jitter (12 KHz – 20 MHz)	F _{out} > 400 MHz		40		fs
RMS Phase Jitter (12 KHz – 20 MHz)	F _{out} > 1000 MHz		25		fs
Note: 1. Phase jitter measured on Agilent 5052B Signal Source Analyzer					

Table 8. Typical Output Phase Noise CharacteristicsVDD= 1.8V, T_A = 25°C, Output Type = CML

Offset frequency	1966.08 MHz	983.04 MHz	491.52 MHz	312.5 MHz	Unit
1 KHz	-89	-94	-99	-102	dBc/Hz
10 KHz	-119	-124	-128	-133	dBc/Hz
100 KHz	-139	-141	-151	-157	dBc/Hz
1 MHz	-149	-154	-160	-161	dBc/Hz
10 MHz	-151	-155	-159	-162	dBc/Hz
20 MHz	-150	-155	-159	-162	dBc/Hz

Typical Output Measured Phase Noise Plots

This section shows three MS1240 performance plots.

Measurement parameters are: VDD = 1.8 V, TA = 25°C, Output Type = CML.

The plots were captured using an Agilent 5052B Signal Source Analyzer.

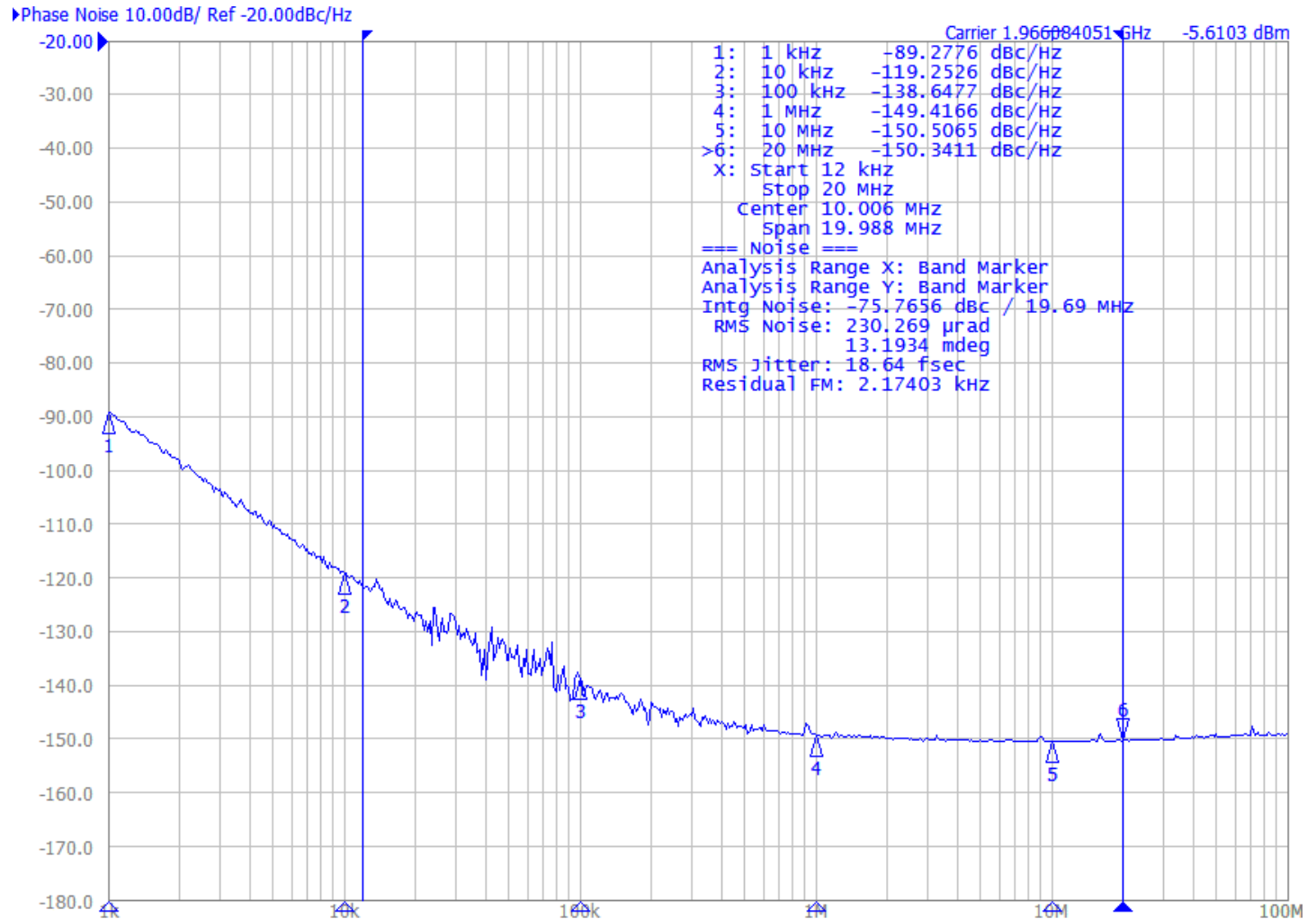


Figure 4. Carrier: 1966.08 MHz

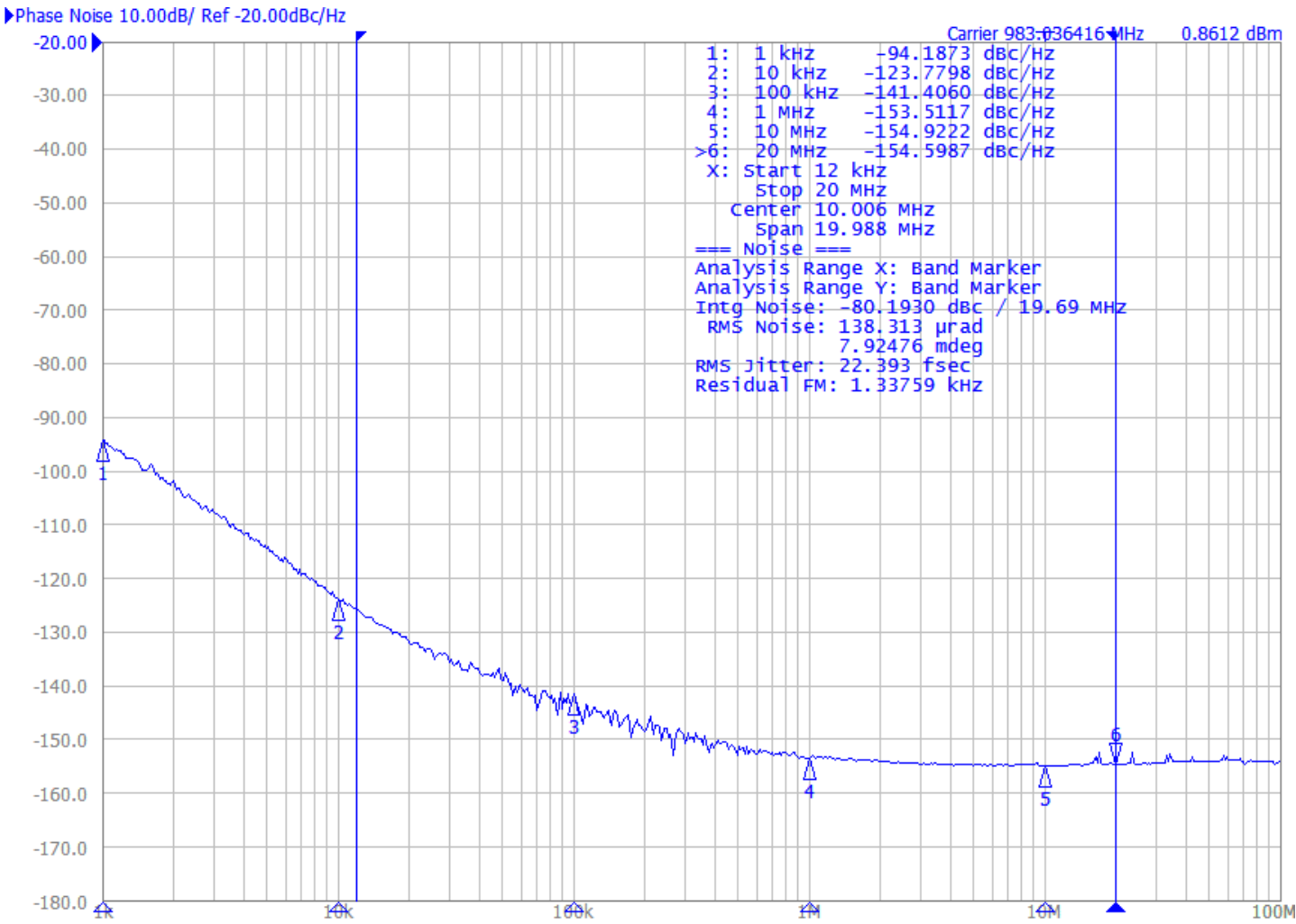


Figure 5. Carrier: 983.04 MHz

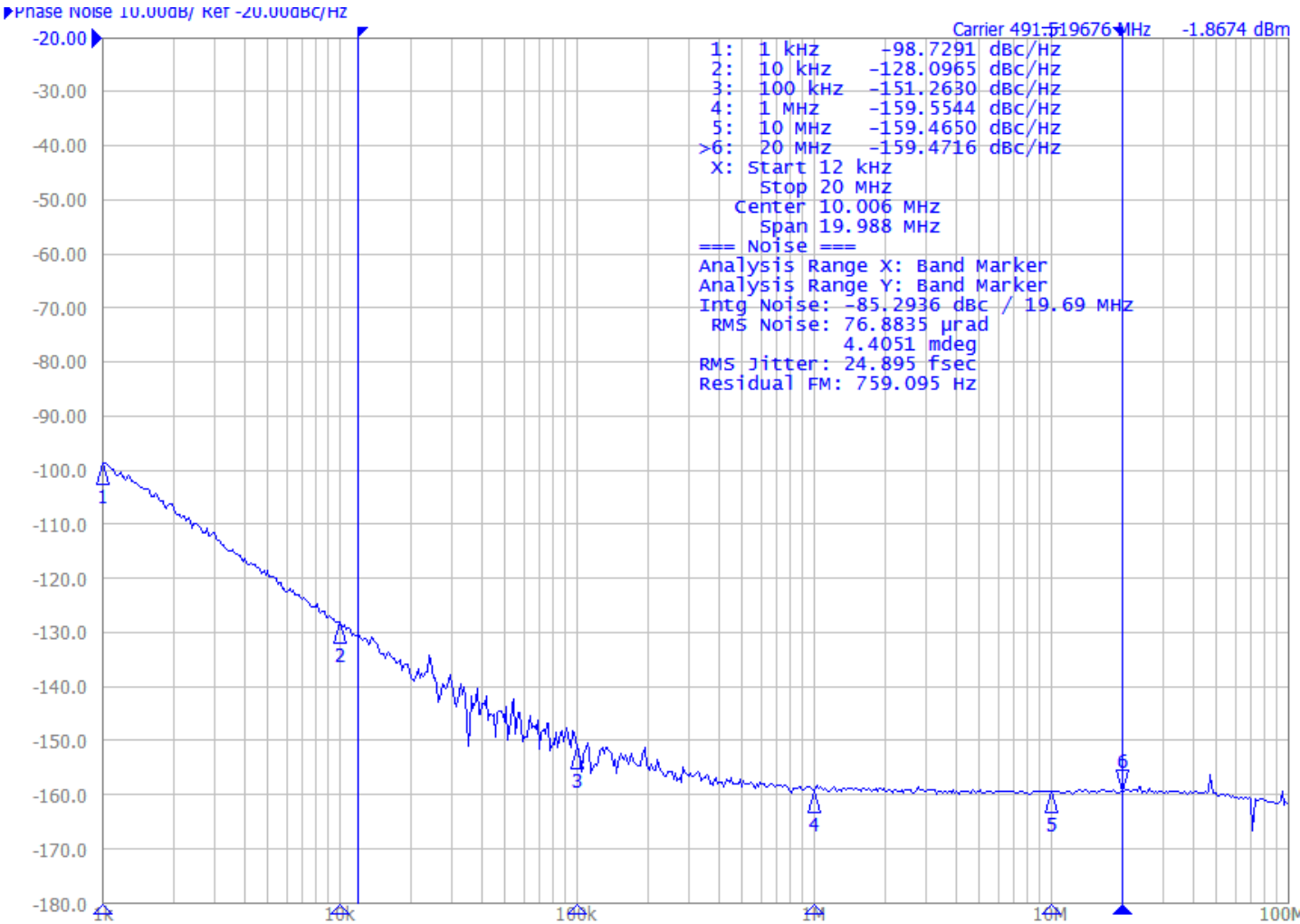


Figure 6. Carrier: 491.52 MHz

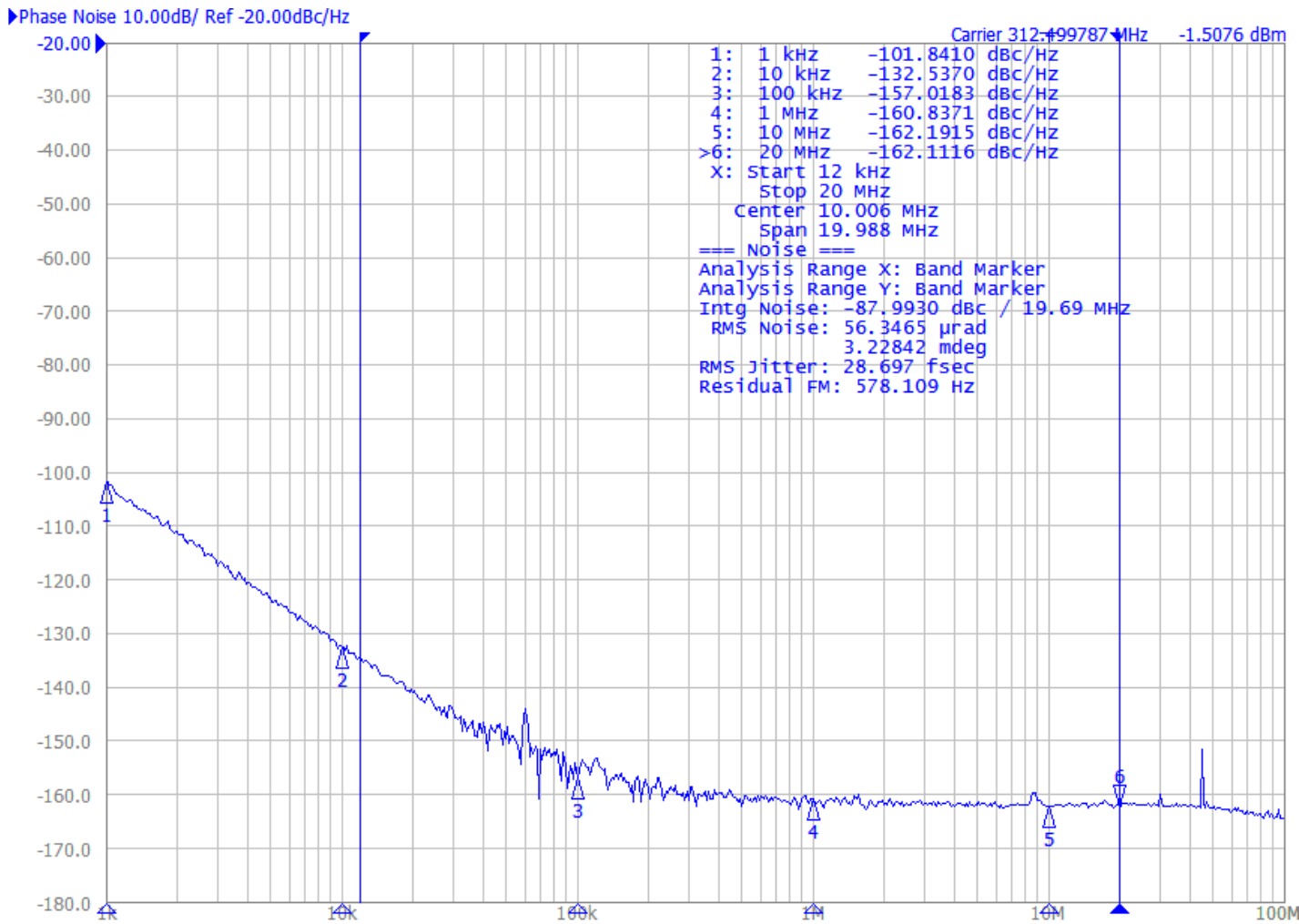


Figure 7. Carrier: 312.5 MHz

Output Terminations

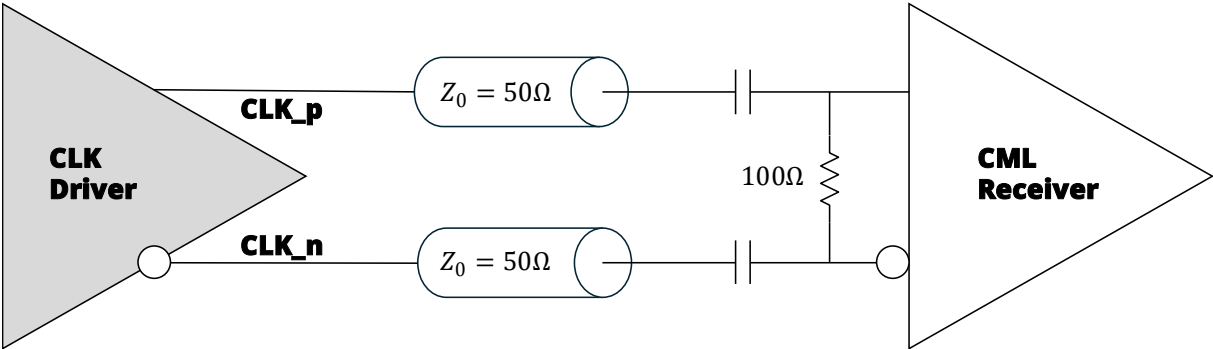


Figure 8. AC-Coupled CML

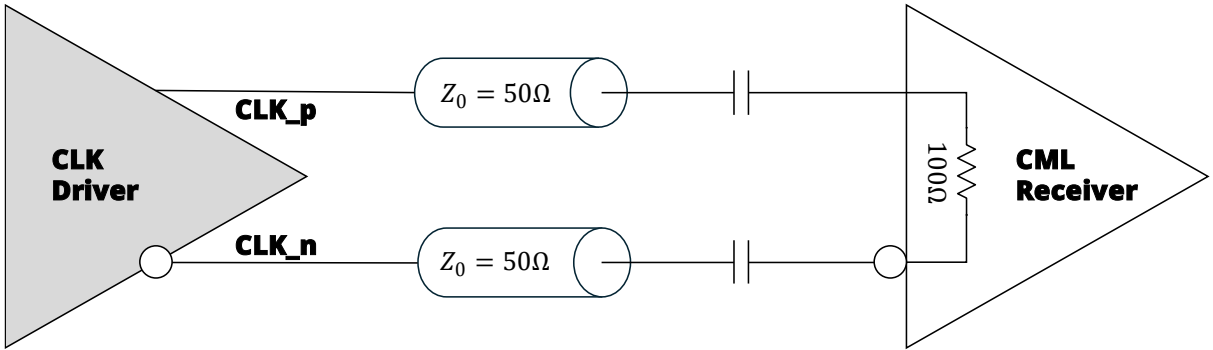


Figure 9. AC-Coupled CML (Receiver Termination)

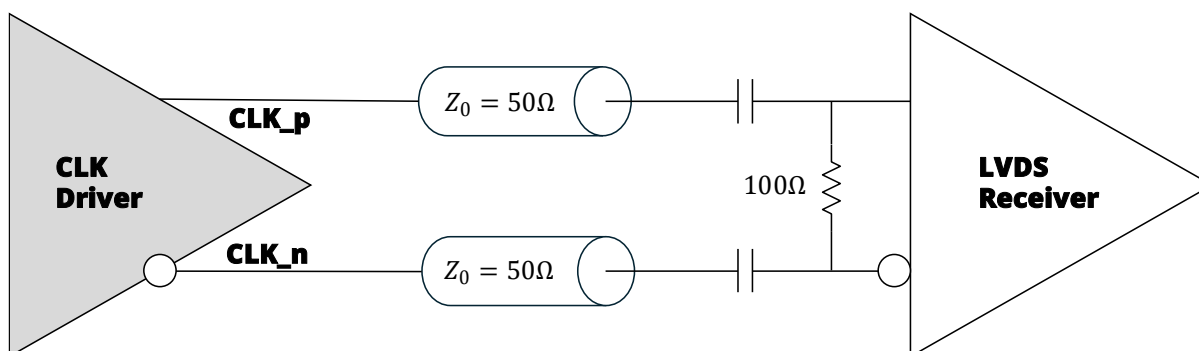


Figure 10. AC-Coupled LVDS

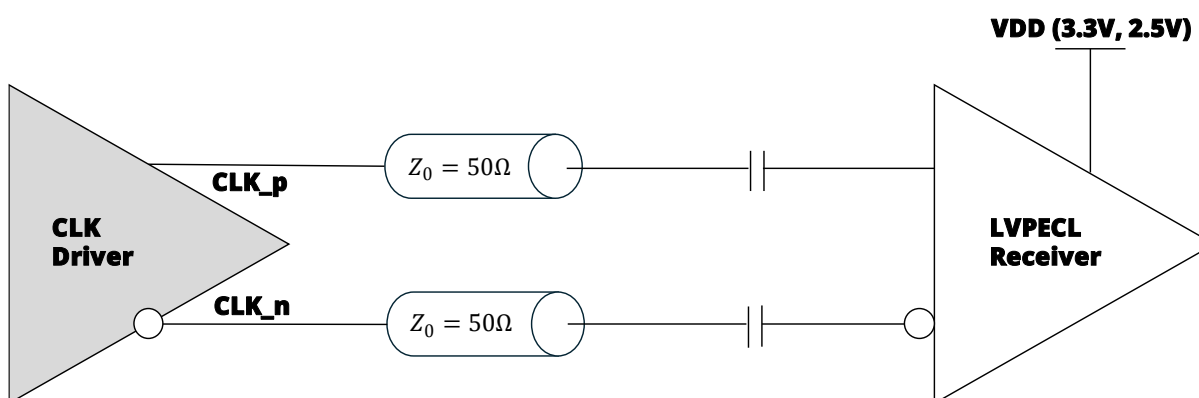


Figure 11. AC-Coupled LVPECL (Integrated Termination)

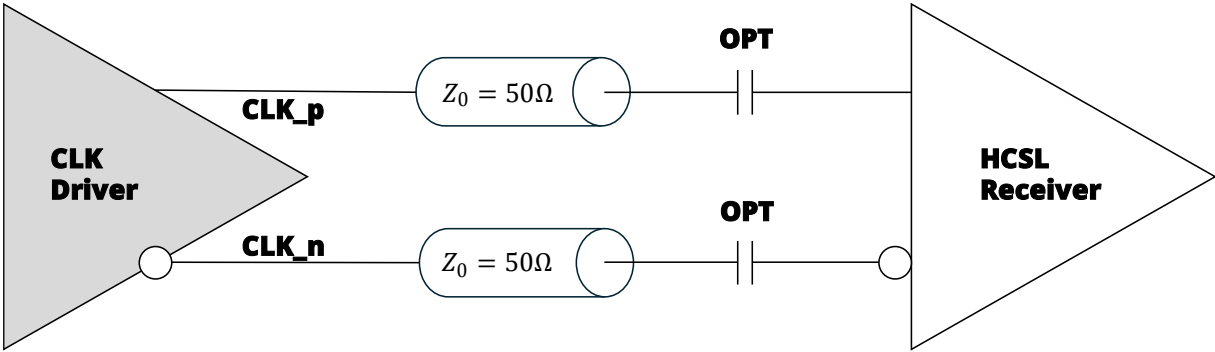


Figure 12. HCSL (Integrated Termination)

Packaging Information

Figure 13 shows the MS1240 packaging drawing.

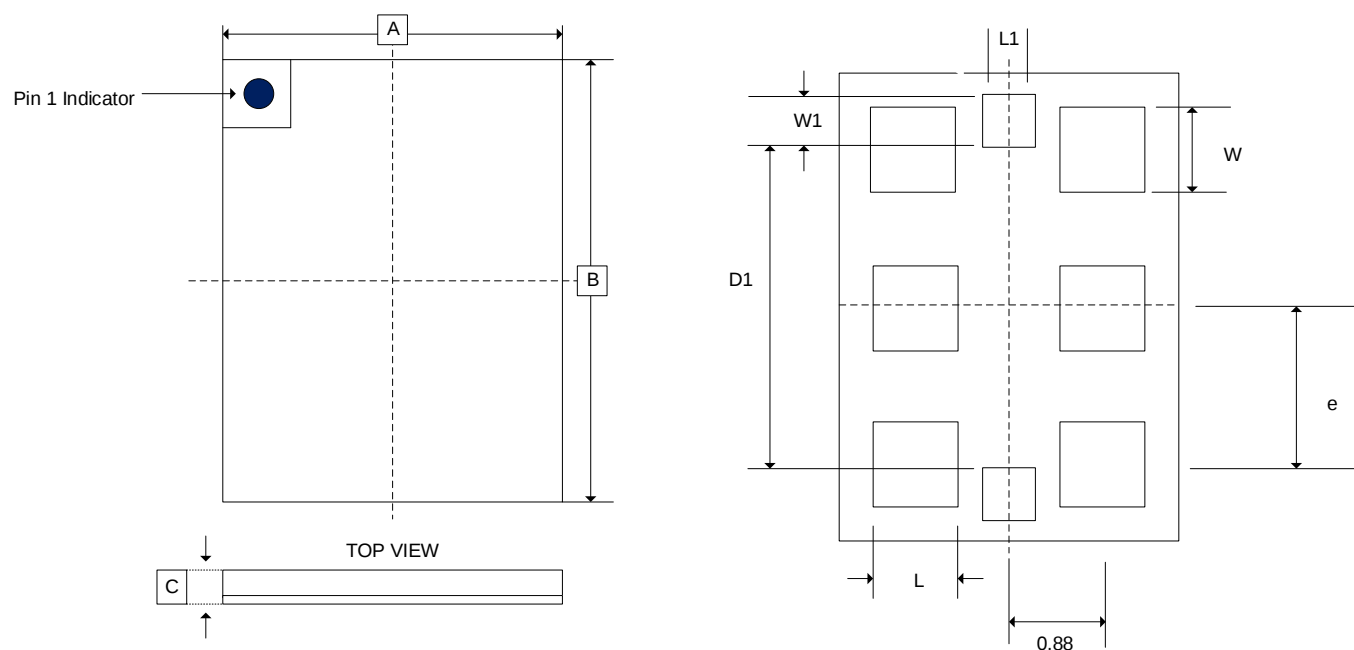


Figure 13. MS1240 Packaging Drawing (3.2mm x 2.5 mm)

Table 9. MS1240 Packaging Dimensions

Dimensions	Min	Nom	Max
A	2.5 BSC		
B	3.2 BSC		
C	0.806	0.946	1.1
W	0.55	0.6	0.65
L	0.5	0.55	0.6
W1	0.35	0.4	0.45
L1	0.35	0.4	0.45
e	1.1 BSC		
D1	2.2 BSC		
Package Edge Tolerance	0.1		
Mold Flatness	0.1		
Coplanarity	0.08		

Packaging Land Pattern

Figure 14 shows the MS1240 PCB land pattern.

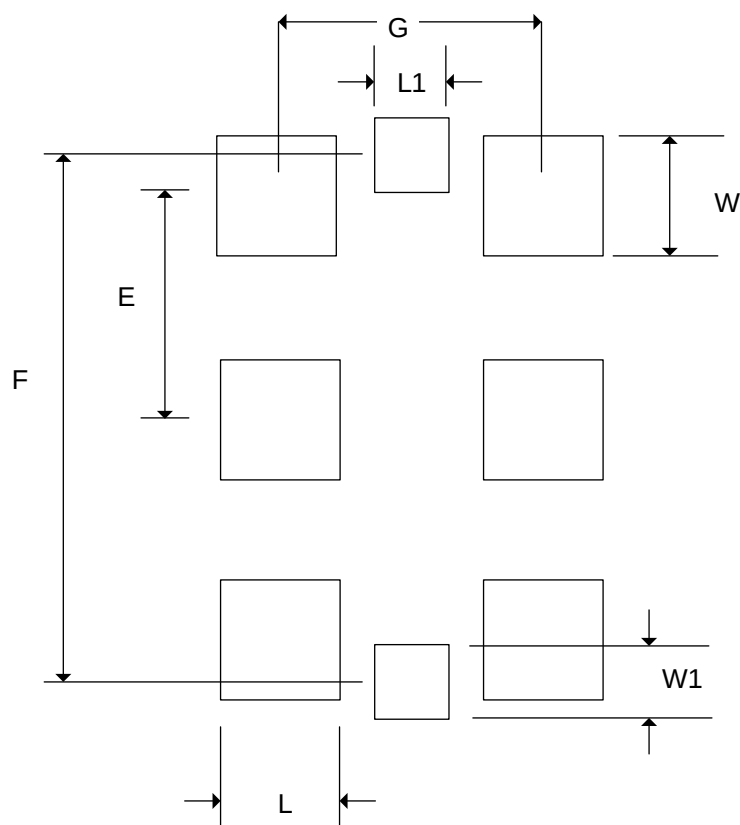


Figure 14. MS1240 Packaging Land Pattern Drawing (3.2mm x 2.5mm)

Table 10. MS1240 Packaging Land Pattern Dimensions

Dimensions	In mm
L	0.7
W	0.7
L1	0.5
W1	0.55
E	1.1
F	2.6
G	1.76

Device Top Marking

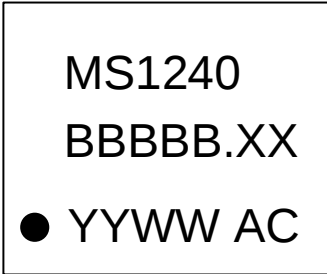


Figure 15. MS1240 Device Top Marking Showing Pin 1

Table 11. MS1240 Device Marking Legend

Line	Position	Description
1	1	Part Number
2	1-5	Wafer Lot Number
	6-7	Wafer #
3	Lot Traceability	
	1	Pin 1 Orientation Mark (Dot),
	2-3	Year (last two digits of the year)
	4-5	Calendar Work Week Number (1-53)
	6-7	Assembly Code

Part Ordering Information

Figure 16 shows a logic tree for ordering each of the three available parts.

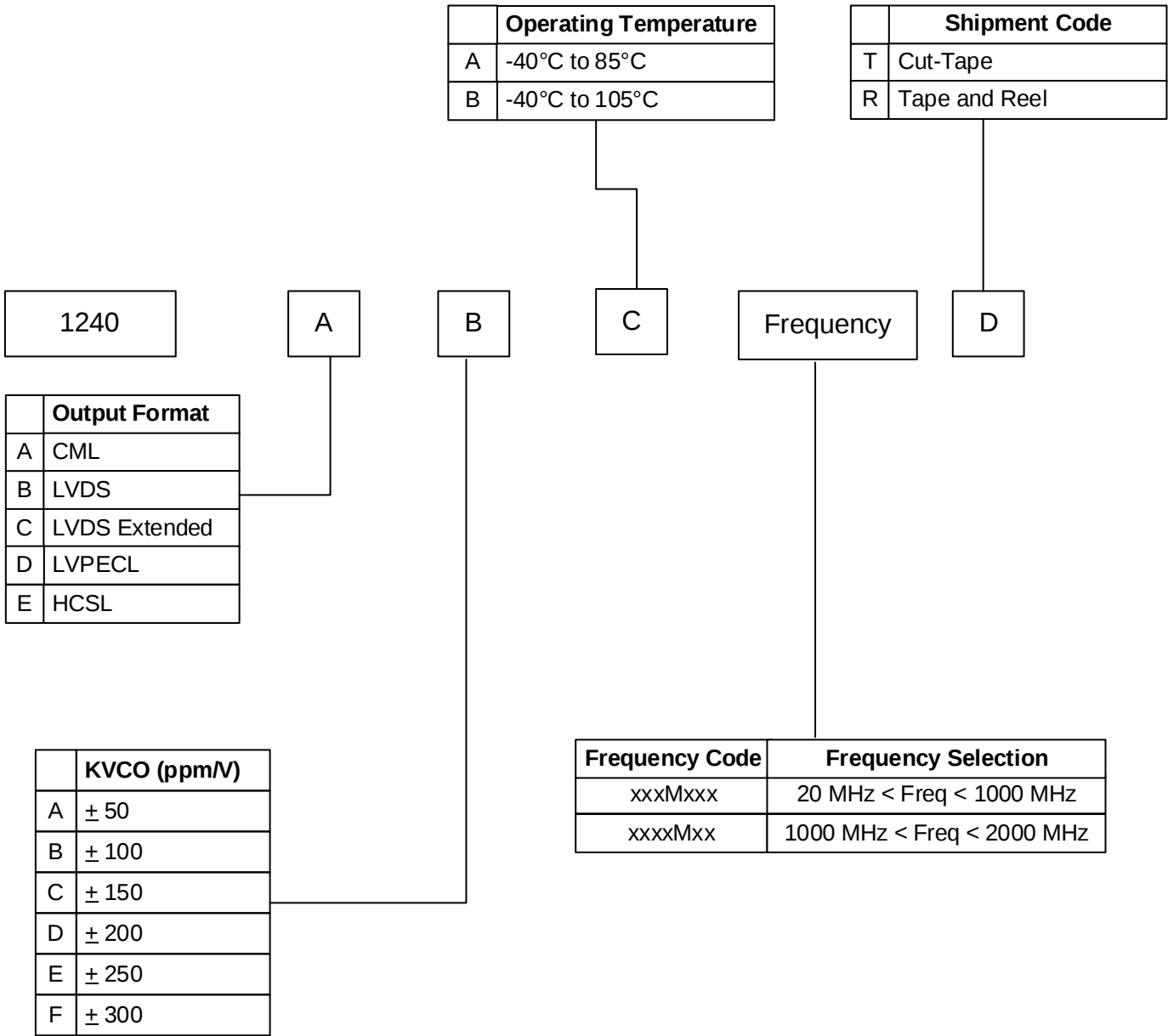


Figure 16. MS1240 Part Ordering Information

IMPORTANT NOTICE AND DISCLAIMER

MIXED-SIGNAL DEVICES INC. PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

Mailing Address: Mixed-Signal Devices Inc, 2 Venture, Suite 300, Irvine, California 92618, USA Copyright © 2023